

SKM 800GA126D



SEMITRANS[®] 4

Trench IGBT Modules

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Features

- Trench = Trenchgate technology
- V_{CEsat} with positive temperature coefficient
- High short circuit capability, self limiting to $6 \times I_C$

Typical Applications*

- AC inverter drives
- UPS
- Electronic welders

Remarks

- $I_{DC} \leq 500A$ limited by terminals



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| Absolute Maximum Ratings | | $T_C = 25^\circ\text{C}$, unless otherwise specified | | |
|--------------------------|--|---|------|------------------|
| Symbol | Conditions | Values | | Units |
| IGBT | | | | |
| V_{CES} | $T_j = 25^\circ\text{C}$ | 1200 | | V |
| I_C | $T_j = 150^\circ\text{C}$ | $T_{case} = 25^\circ\text{C}$ | 960 | A |
| | | $T_{case} = 80^\circ\text{C}$ | 620 | A |
| I_{CRM} | $I_{CRM} = 2 \times I_{Cnom}$ | 1200 | | A |
| V_{GES} | | ± 20 | | V |
| t_{psc} | $V_{CC} = 600\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125^\circ\text{C}$ $V_{CES} < 1200\text{ V}$ | 10 | | μs |
| Inverse Diode | | | | |
| I_F | $T_j = 150^\circ\text{C}$ | $T_{case} = 25^\circ\text{C}$ | 680 | A |
| | | $T_{case} = 125^\circ\text{C}$ | 470 | A |
| I_{FRM} | $I_{FRM} = 2 \times I_{Fnom}$ | 1200 | | A |
| I_{FSM} | $t_p = 10\text{ ms}; \sin.$ | $T_j = 150^\circ\text{C}$ | 3600 | A |
| Module | | | | |
| $I_{t(RMS)}$ | | 500 | | A |
| T_{vj} | | - 40 ... + 150 | | $^\circ\text{C}$ |
| T_{stg} | | - 40 ... + 125 | | $^\circ\text{C}$ |
| V_{isol} | AC, 1 min. | 4000 | | V |

| Characteristics | | $T_C = 25^\circ\text{C}$, unless otherwise specified | | | |
|-----------------|---|---|------|----------|------------------|
| Symbol | Conditions | min. | typ. | max. | Units |
| IGBT | | | | | |
| $V_{GE(th)}$ | $V_{GE} = V_{CE}, I_C = 16\text{ mA}$ | 5 | 5,8 | 6,5 | V |
| I_{CES} | $V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$ | $T_j = 25^\circ\text{C}$ | 0,2 | 0,6 | mA |
| | | $T_j = 125^\circ\text{C}$ | | | mA |
| V_{CE0} | | $T_j = 25^\circ\text{C}$ | 1 | 1,15 | V |
| | | $T_j = 125^\circ\text{C}$ | 0,9 | | V |
| r_{CE} | $V_{GE} = 15\text{ V}$ | $T_j = 25^\circ\text{C}$ | 1,2 | 1,7 | $\text{m}\Omega$ |
| | | $T_j = 125^\circ\text{C}$ | 1,8 | | $\text{m}\Omega$ |
| $V_{CE(sat)}$ | $I_{Cnom} = 600\text{ A}, V_{GE} = 15\text{ V}$ | $T_j = 25^\circ\text{C}_{chiplev.}$ | 1,7 | 2,15 | V |
| | | $T_j = 125^\circ\text{C}_{chiplev.}$ | 2 | | V |
| C_{ies} | $V_{CE} = 25, V_{GE} = 0\text{ V}$ | $f = 1\text{ MHz}$ | 42 | | nF |
| C_{oes} | | | 3,3 | | nF |
| C_{res} | | | 3,1 | | nF |
| Q_G | $V_{GE} = -8\text{ V} - +20\text{ V}$ | 5200 | | nC | |
| R_{Gint} | $T_j = ^\circ\text{C}$ | 1,25 | | Ω | |
| $t_{d(on)}$ | $R_{Gon} = 3\ \Omega$ | $V_{CC} = 600\text{ V}$ $I_C = 600\text{ A}$ | 220 | | ns |
| t_r | | | 100 | | ns |
| E_{on} | | | 65 | | mJ |
| $t_{d(off)}$ | $R_{Goff} = 3\ \Omega$ | $T_j = 125^\circ\text{C}$ $V_{GE} = \pm 15\text{ V}$ | 860 | | ns |
| t_f | | | 135 | | ns |
| E_{off} | | | 95 | | mJ |
| $R_{th(j-c)}$ | per IGBT | 0,042 | | K/W | |

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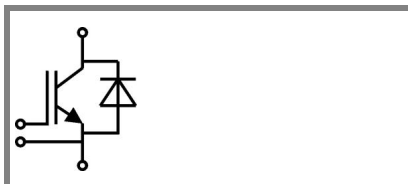
Remarks

- $I_{DC} \leq 500A$ limited by terminals

| Characteristics | | | | | |
|----------------------|----------------------------------|---------------------------------|-----------|-------|------------|
| Symbol | Conditions | min. | typ. | max. | Units |
| Inverse Diode | | | | | |
| $V_F = V_{EC}$ | $I_{Fnom} = 600 A; V_{GE} = 0 V$ | $T_j = 25 ^\circ C_{chiplev.}$ | 1,6 | 1,8 | V |
| | | $T_j = 125 ^\circ C_{chiplev.}$ | 1,6 | 1,8 | V |
| V_{F0} | | $T_j = 25 ^\circ C$ | 1 | 1,1 | V |
| | | $T_j = 125 ^\circ C$ | 0,8 | 0,9 | V |
| r_F | | $T_j = 25 ^\circ C$ | 1 | 1,2 | m Ω |
| | | $T_j = 125 ^\circ C$ | 1,3 | 1,5 | m Ω |
| I_{RRM} | $I_F = 600 A$ | $T_j = 125 ^\circ C$ | 540 | | A |
| Q_{rr} | $di/dt = 6000 A/\mu s$ | | 125 | | μC |
| E_{rr} | $V_{GE} = -15 V; V_{CC} = 600 V$ | | 59 | | mJ |
| $R_{th(j-c)D}$ | per diode | | | 0,09 | K/W |
| Module | | | | | |
| L_{CE} | | | 15 | 20 | nH |
| R_{CC+EE} | res., terminal-chip | $T_{case} = 25 ^\circ C$ | 0,18 | | m Ω |
| | | $T_{case} = 125 ^\circ C$ | 0,22 | | m Ω |
| $R_{th(c-s)}$ | per module | | | 0,038 | K/W |
| M_s | to heat sink M6 | | 3 | 5 | Nm |
| M_t | to terminals M6 (M4) | | 2,5 (1,1) | 5 (2) | Nm |
| w | | | | 330 | g |

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



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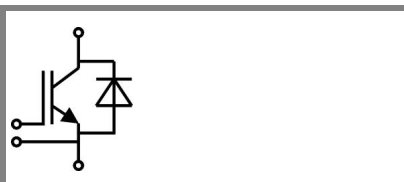
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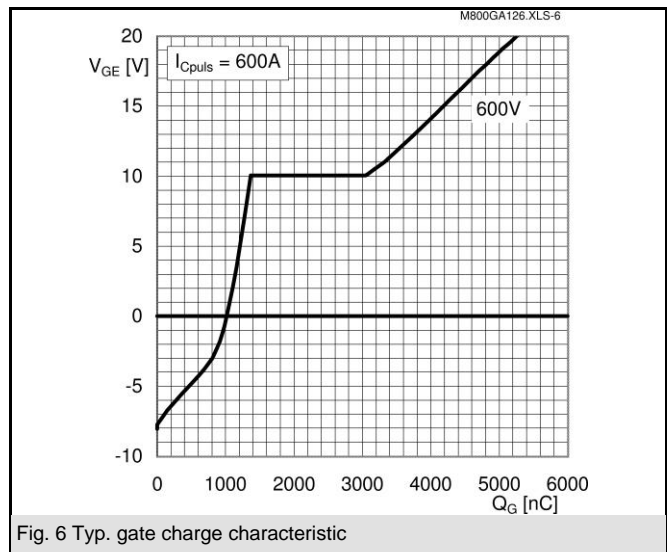
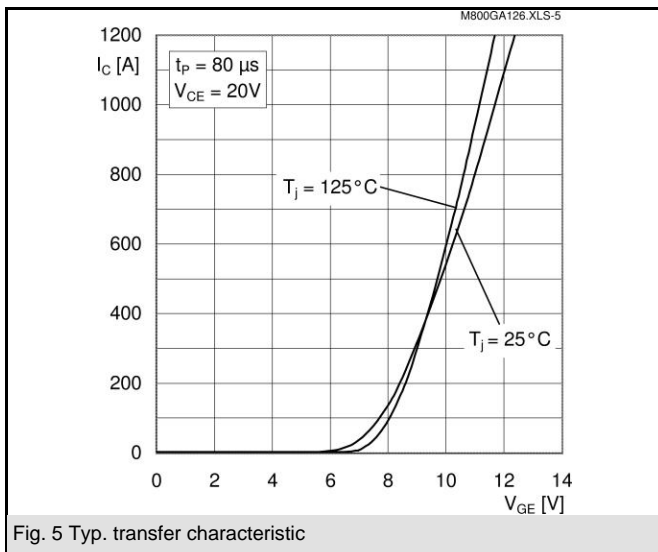
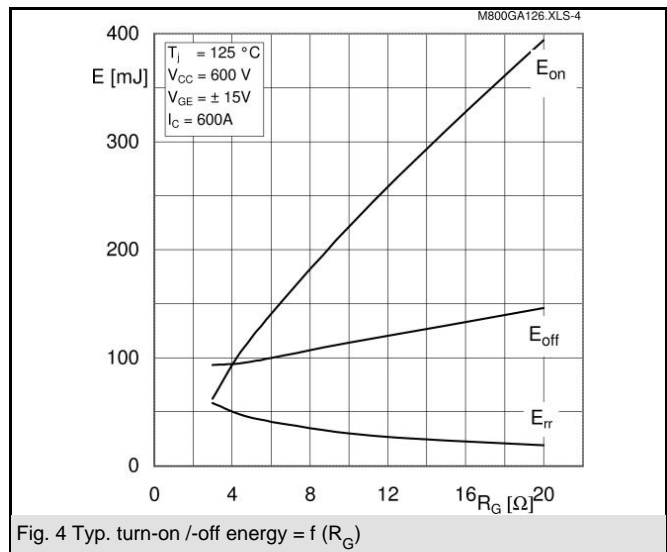
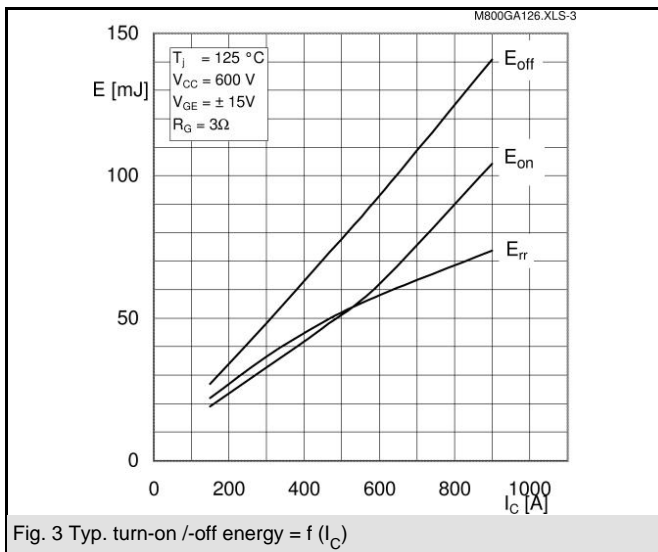
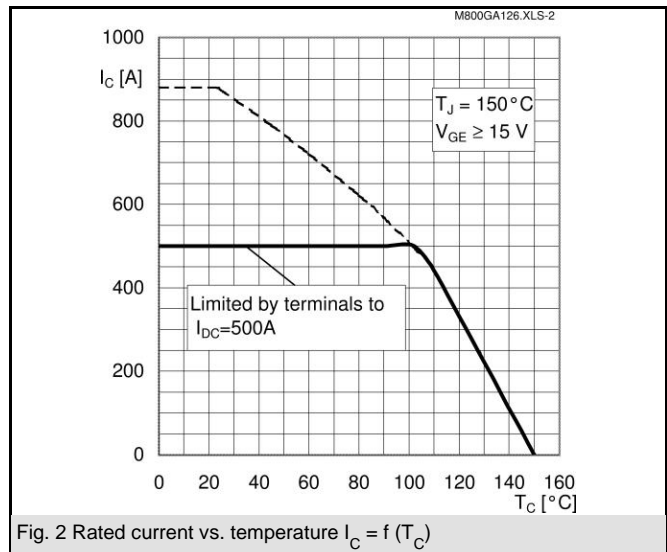
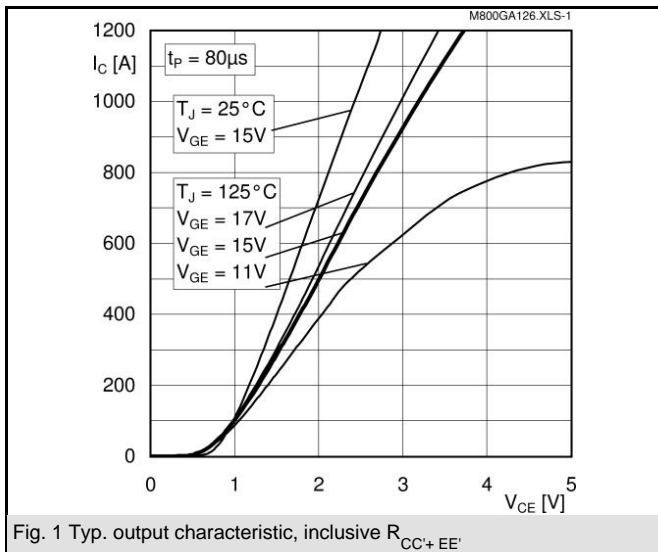
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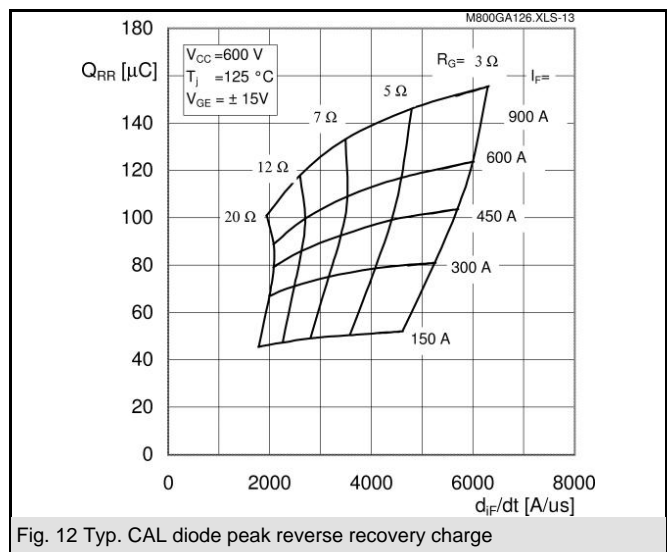
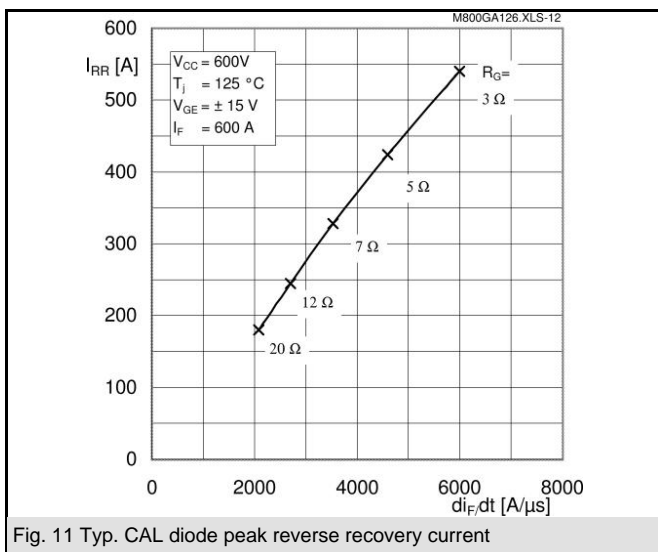
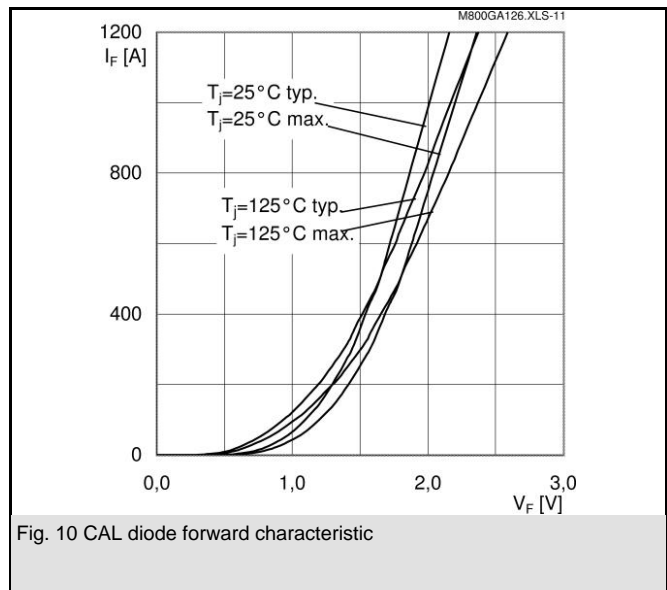
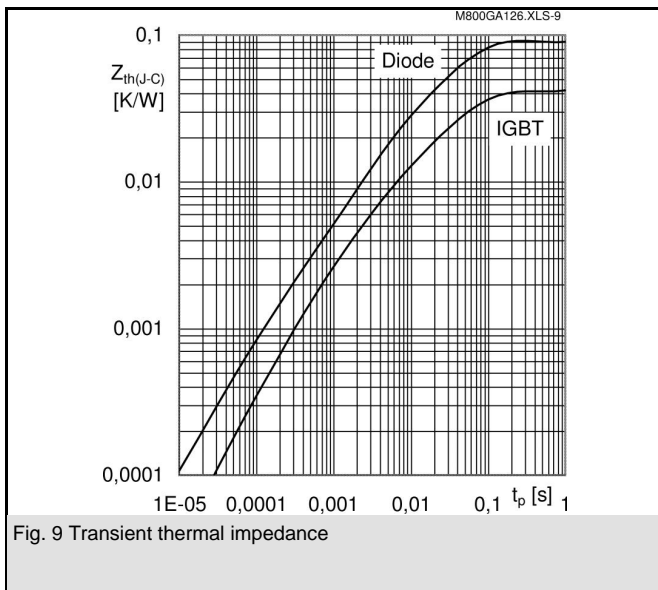
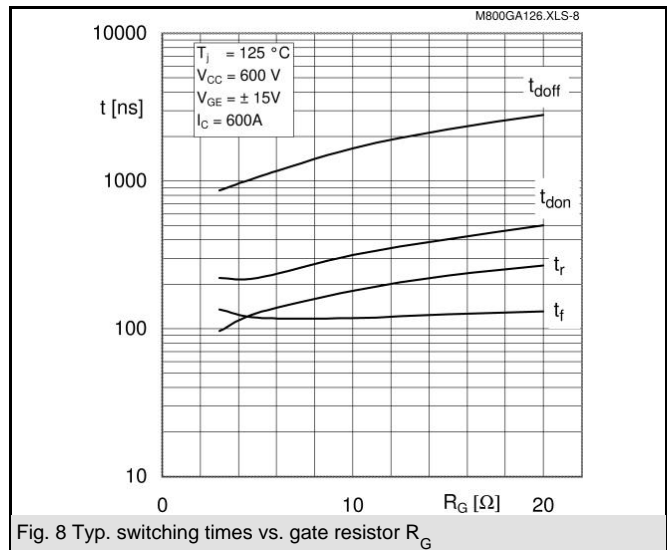
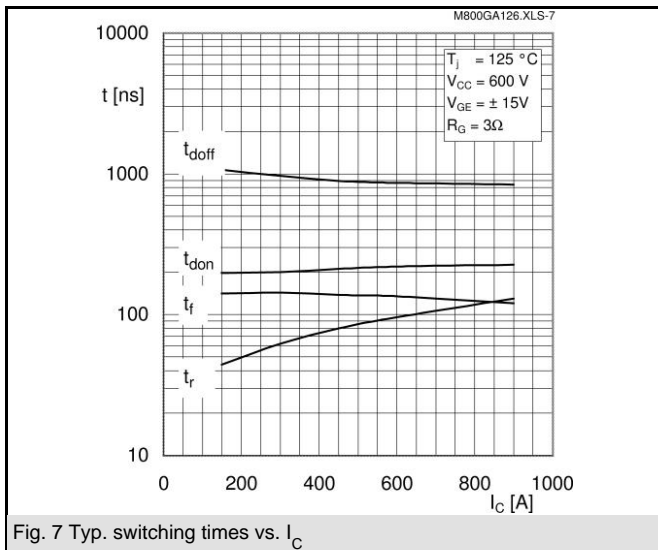
- $I_{DC} \leq 500A$ limited by terminals

| Z_{th} | | Values | Units |
|---------------------|------------|--------|-------|
| Symbol | Conditions | | |
| $Z_{th(j-c)I}$ | | | |
| $R_{\theta j-c}$ | $i = 1$ | 30 | mk/W |
| $R_{\theta j-c}$ | $i = 2$ | 9,5 | mk/W |
| $R_{\theta j-c}$ | $i = 3$ | 2,2 | mk/W |
| $R_{\theta j-c}$ | $i = 4$ | 0,3 | mk/W |
| $\tau_{\theta j-c}$ | $i = 1$ | 0,1043 | s |
| $\tau_{\theta j-c}$ | $i = 2$ | 0,009 | s |
| $\tau_{\theta j-c}$ | $i = 3$ | 0,0015 | s |
| $\tau_{\theta j-c}$ | $i = 4$ | 0,004 | s |
| $Z_{th(j-c)D}$ | | | |
| $R_{\theta j-c}$ | $i = 1$ | 62 | mk/W |
| $R_{\theta j-c}$ | $i = 2$ | 23 | mk/W |
| $R_{\theta j-c}$ | $i = 3$ | 4,2 | mk/W |
| $R_{\theta j-c}$ | $i = 4$ | 0,8 | mk/W |
| $\tau_{\theta j-c}$ | $i = 1$ | 0,0566 | s |
| $\tau_{\theta j-c}$ | $i = 2$ | 0,0166 | s |
| $\tau_{\theta j-c}$ | $i = 3$ | 0,0015 | s |
| $\tau_{\theta j-c}$ | $i = 4$ | 0,0002 | s |



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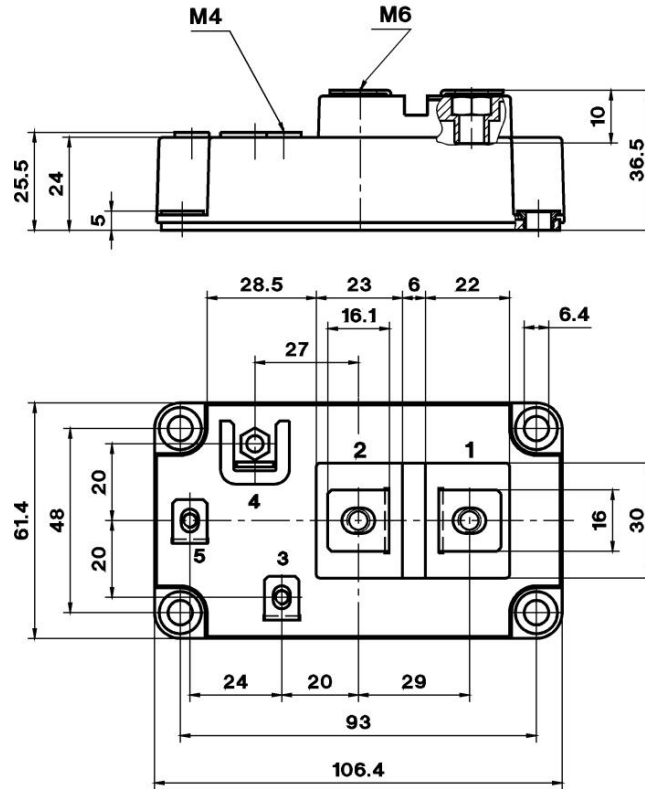


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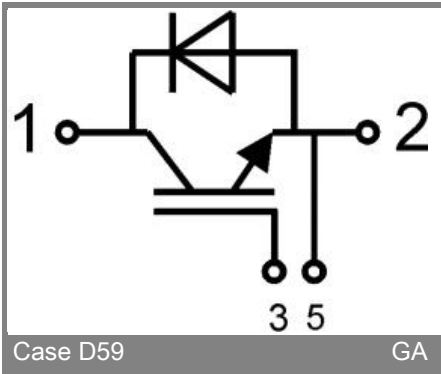
UL Recognized

CASED59

File 63 532



Case D 59



Case D59

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